



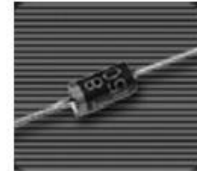
SYNSEMI SEMICONDUCTOR

HER201G thru HER208G

2.0 Amps. Glass Passivated High Efficient Rectifiers
Voltage Range 50 to 1000 Volts Forward Current 2.0 Amperes

Features

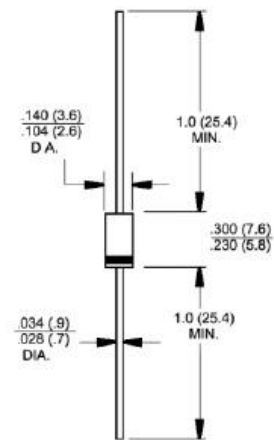
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ High reliability
- ◆ High surge current capability



DO-204AC (DO-15)

Mechanical Data

- ◆ Case: Molded plastic DO-204AC(DO-15)
- ◆ Epoxy: UL 94V-O rate flame retardant
- ◆ Lead: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- ◆ Polarity: Color band denotes cathode end
- ◆ High temperature soldering guaranteed: 250°C/10 seconds .375" (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ◆ Mounting position: Any
- ◆ Weight: 0.014 ounce, 0.395 gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Parameter	Symbols	HER 201G	HER 202G	HER 203G	HER 204G	HER 205G	HER 206G	HER 207G	HER 208G	Units	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	800	1000	Volts	
Maximum RMS voltage	V_{RMS}	35	70	140	210	280	420	560	700	Volts	
Maximum DC blocking voltage	V_{DC}	50	100	200	300	400	600	800	1000	Volts	
Maximum average forward rectified current .375" (9.5mm) lead length @ $T_a = 55^\circ\text{C}$	$I_{F(AV)}$	2.0								Amps	
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	60.0								Amps	
Maximum instantaneous forward voltage @ 2.0A	V_F	1.0				1.3	1.7			Volts	
Maximum DC reverse current @ $T_a = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_a = 125^\circ\text{C}$	I_R	5.0				150					μA μA
Maximum reverse recovery time (Note 1)	t_{rr}	50				75				nS	
Typical junction capacitance (Note 2)	C_j	50				30				pF	
Operating temperature range	T_j	-65 to +150								$^\circ\text{C}$	
Storage temperature range	T_{STG}	-65 to +150								$^\circ\text{C}$	

- Notes: 1. Reverse Recovery Test Conditions: $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

HER201G thru HER208G

RATINGS AND CHARACTERISTIC CURVES

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

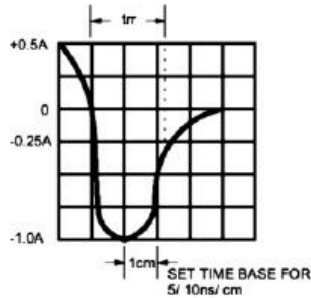
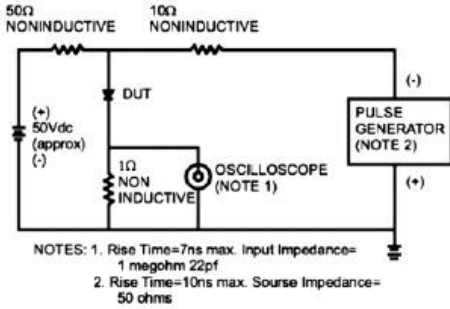


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

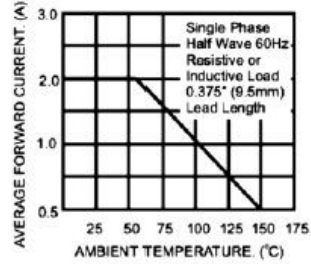


FIG.3- TYPICAL REVERSE CHARACTERISTICS

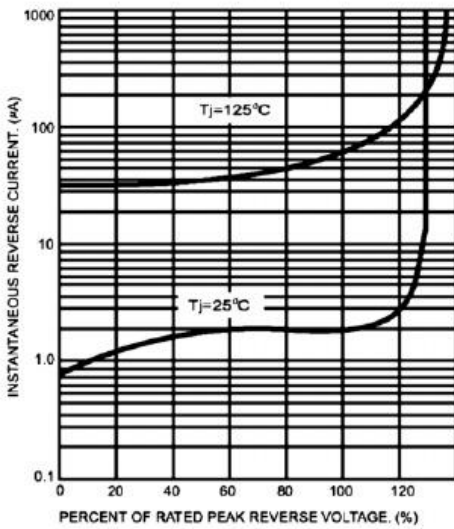


FIG.4- TYPICAL FORWARD CHARACTERISTICS

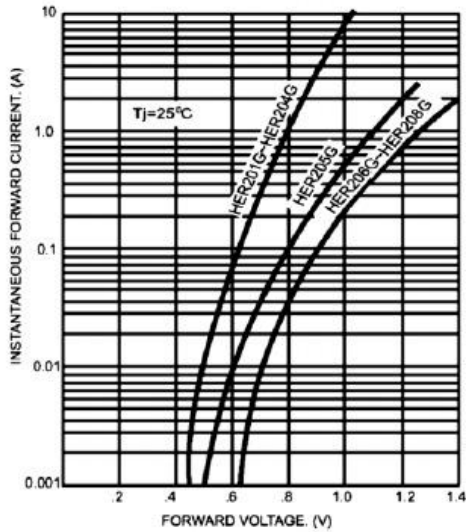


FIG.5- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

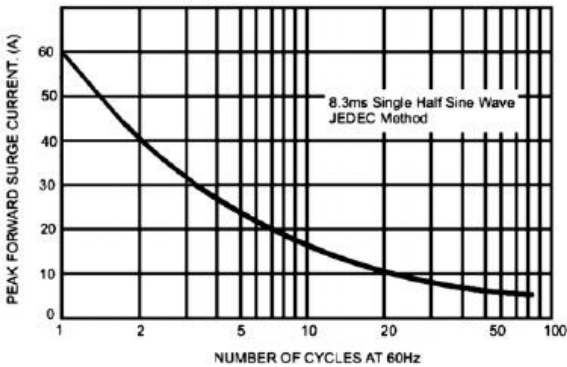


FIG.6- TYPICAL JUNCTION CAPACITANCE

